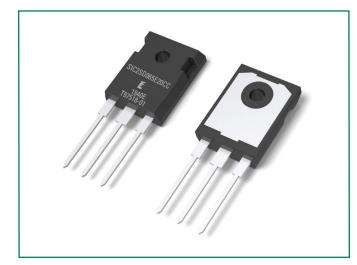
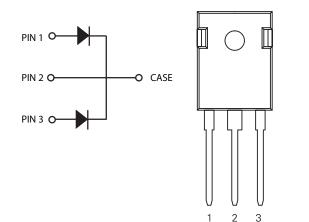
LSIC2SD065E20CCA 650 V, 20 A SiC Schottky Barrier Diode 🛛 🛤 AUTOMOTIVE GRADE HF ROHS 🔗



Circuit Diagram TO-247-3L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C. maximum operating junction temperature
- Extremely fast, temperature-independent

Excellent surge capability

- switching behaviorDramatically reducedswitching leases
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

supplies

 Boost diodes in PFC or DC/DC stages

• Switch-mode power

- Solar inverters
 - Industrial motor drives
 - EV charging stations
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

Maximum Ratings

Maximum Ratings					
Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current (Per Leg/Component)		$T_c = 25 \text{ °C}$	27 / 54	A	
	F	T _c = 147 °C	10 / 20		
Non-Repetitive Forward Surge Current (Per Leg)	I _{FSM}	$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half sine pulse}$	50	А	
Power Dissipation (Per Leg/Component)	D	$T_c = 25 \text{ °C}$	100 / 200	W	
	P _{Tot}	$T_c = 110 \ ^{\circ}C$	43 / 86		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

Electrical Characteristics (T₁ = 25 °C unless otherwise specified)

			Value				
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Voltage		I _F = 10 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 10 A, T _J = 175 °C	-	1.85	-		
Reverse Current	I _R	V _R = 650 V, T _J = 25 °C	-	<1	50		
		$V_{_{\rm R}} = 650 \text{ V}, \text{ T}_{_{ m J}} = 175 \ ^{\circ}\text{C}$	-	25	-	μΑ	
Total Capacitance		$V_{_{\mathrm{R}}}$ = 1 V, f = 1 MHz	-	470	-		
	С	V _R = 200 V, f = 1 MHz	-	60	-	pF	
		V _R = 400 V, f = 1 MHz	-	43	43 -		
Total Capacitive Charge	Q _c	$V_{R} = 400 V$, $Q_{C} = \int_{0}^{V_{R}} C(V) dV$	-	30	-	nC	

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance (Per Leg/Component)	R _{eic}	1.50 / 0.75	°C/W

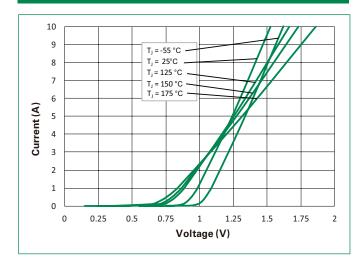


Figure 1: Typical Foward Characteristics

Figure 2: Typical Reverse Characteristics

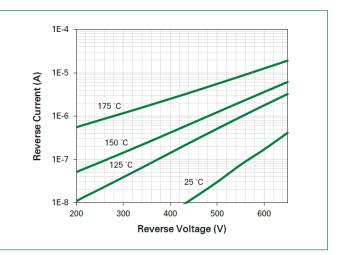


Figure 3: Power Derating

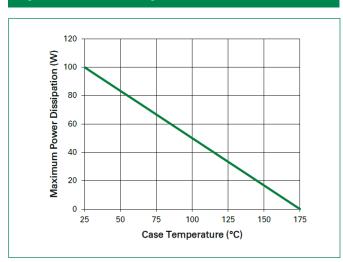


Figure 5: Capacitance vs. Reverse Voltage

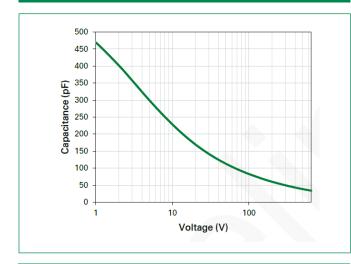


Figure 7: Stored Energy vs. Reverse Voltage

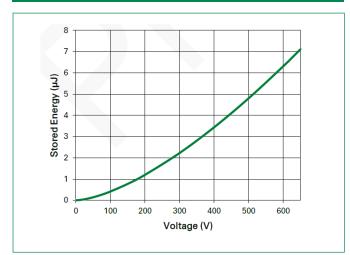


Figure 4: Current Derating

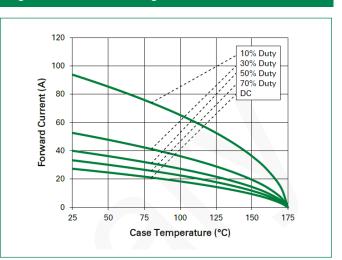


Figure 6: Capacitive Charge vs. Reverse Voltage

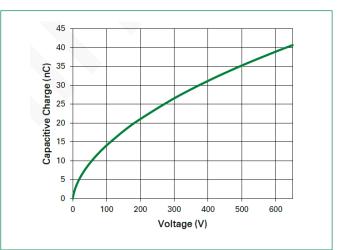
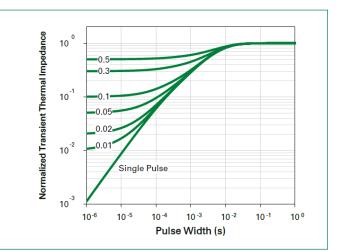


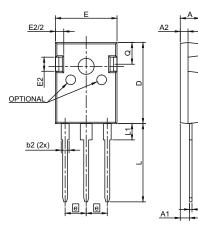
Figure 8: Transient Thermal Impedance

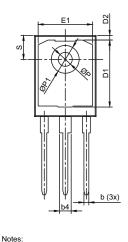


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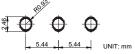
GEN2 SiC Schottky Diode LSIC2SD065E20CCA, 650 V, 20 A, TO-247-3L

Package Dimensions TO-247-3L





Recommended Hole Pattern Layout



1. Dimensions are in millimeters
2. Dimension D, E do not include mold flash. Mold flash
shall not exceed 0.127 mm per side. These measured
at the outermost extreme of plastic body.
3.øP to have a maximum draft angle of 1.5° to the top
of the part with a maximum hole diameter of 0.154"

	Symbol	Millimeters			
		Min	Nom	Max	
	А	4.80	5.03	5.20	
	A1	2.25	2.38	2.54	
	A2	1.85	1.98	2.11	
	b	0.99	-	1.40	
	b2	1.65	-	2.39	
	b4	2.59	-	3.43	
	С	0.38	0.64	0.89	
	D	20.80	20.96	21.34	
	D1	13.50	-	-	
	D2	0.51	1.19	1.35	
	е	5.44 BSC			
	E	15.75	15.90	16.13	
	E1	13.06	14.02	14.15	
	E2	4.19	4.32	4.83	
	L	19.81	20.19	20.57	
	L1	3.81	4.19	4.45	
_	øP	3.55	3.61	3.66	
	øP1	7.06	7.19	7.32	
_	Q	5.49	5.61	6.20	
	S	6.05	6.17	6.30	

Part Numbering and Marking System

SIC

2

SD

065

Е

20 CC

Υ

Х

WW



= SiC	
= Gen2	

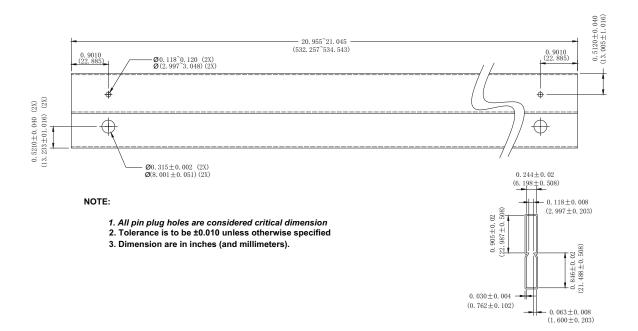
- = Schottky Diode
- = Voltage Rating (650 V)
- = TO-247-3L
- = Current Rating (20 A)
- = Common Cathode
- = Year
- = Week
- = Special Code
- ZZZZZZ-ZZ = Lot Number

Packing Options						
Part Number	Marking	Packing Mode	M.O.Q			
LSIC2SD065E20CCA	SIC2SD065E20CC	Tube (30pcs)	450			



GEN2 SiC Schottky Diode LSIC2SD065E20CCA, 650 V, 20 A, TO-247-3L

Packing Specification TO-247-3L



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